## NSN 5962-01-176-0865

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Body Length:	
0.840 inches	
Body Width:	
	es and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power D	issipation Rating:
794.0 milliwatts	
Operating Tempura	ature Range:
-55.0/+125.0 degree	es celsius
Storage Tempurate	ure Range:
-65.0/+150.0 degree	elsius
Features Provided	
Hermetically sealed	and programmable and bipolar and monolithic
Inclosure Material:	
Ceramic and glass	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	
Transistor-transistor	logic
Input Circuit Patter	m:
10 input	
Case Outline Sour	ce And Designator:
D-2 mil-m-38510	
Terminal Surface 1	reatment:
Solder	
Voltage Rating And	d Type Per Characteristic:
-0.5 volts power so	urce and 7.0 volts power source
Time Rating Per C	nacteristic:
85.00 nanoseconds	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	pe:
Prom	
Memory Capacity:	
Unknown	
Terminal Type And	Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

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